

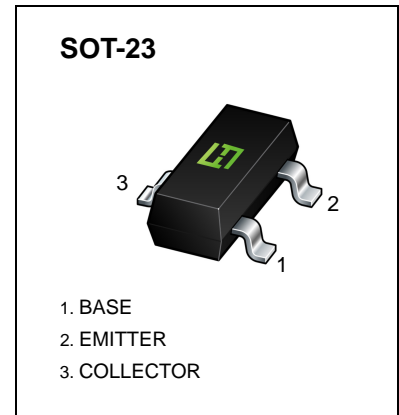
FEATURES

- Complementary Type FMMT593

Marking :493

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	120	V
V _{CEO}	Collector-Emitter Voltage	100	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	1000	mA
P _C	Collector Power Dissipation	250	mW
R _{θJA}	Thermal Resistance From Junction To Ambient	500	°C/W
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

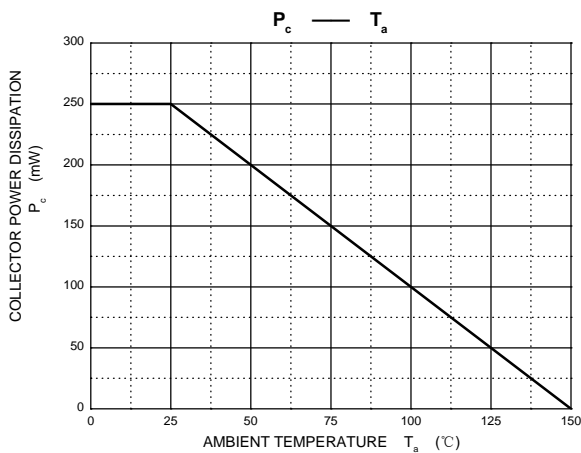
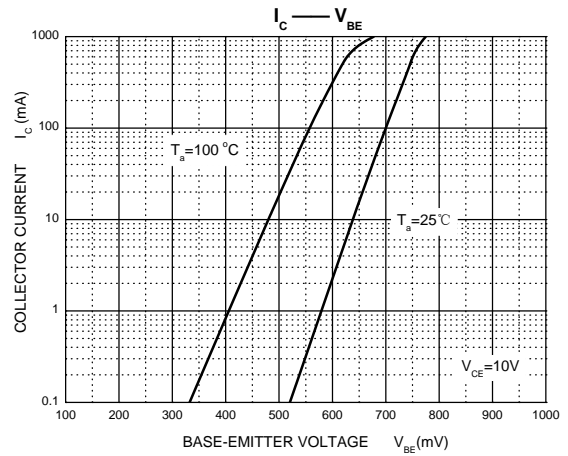
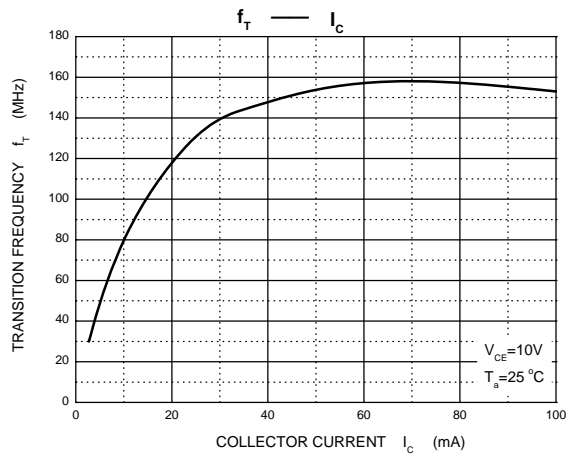
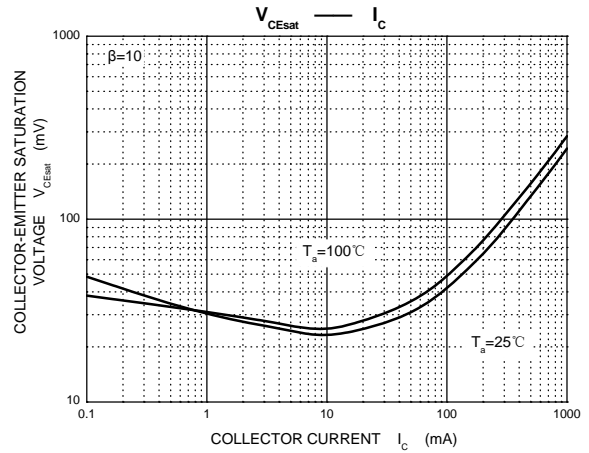
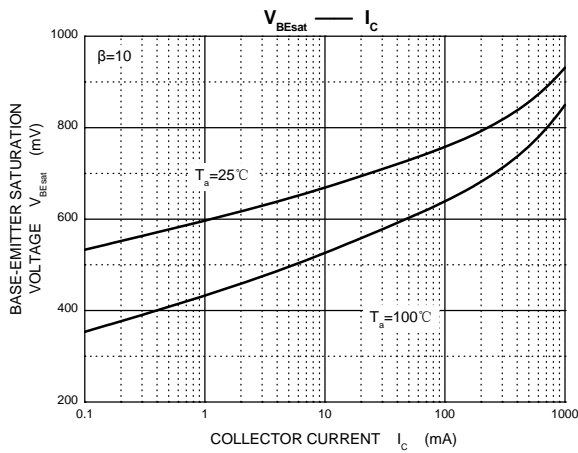
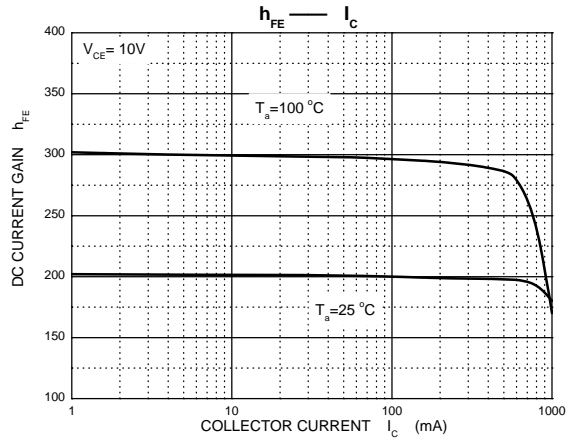
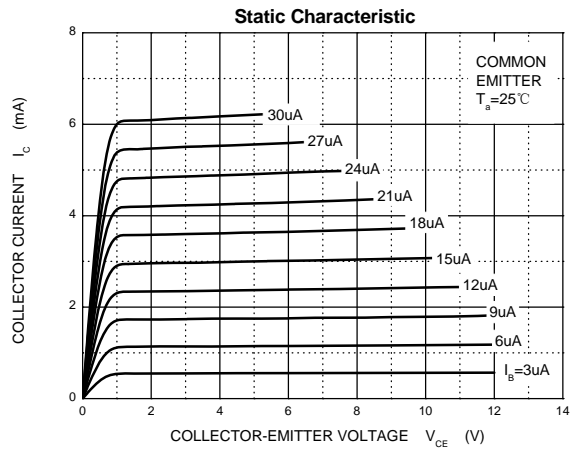


ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

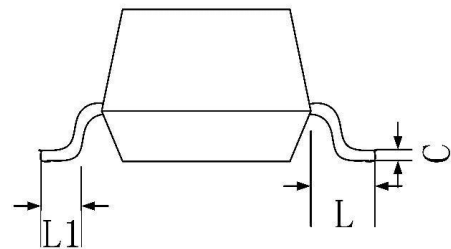
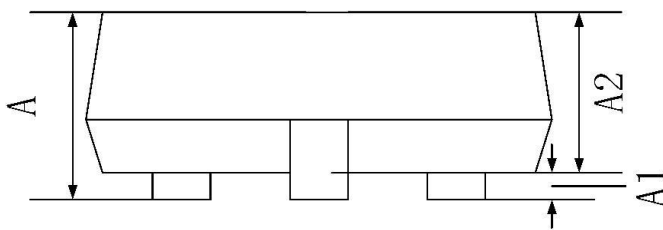
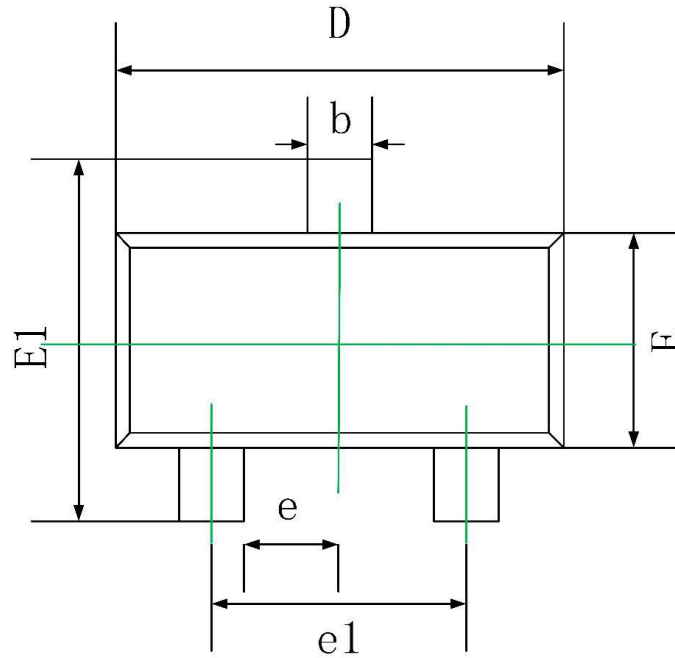
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100μA, I _E =0	120			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =10mA, I _B =0	100			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =100μA, I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =100V, I _E =0			0.1	μA
Collector cut-off current	I _{CES}	V _{CE} =100V, I _E =0			0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =4V, I _C =0			0.1	μA
DC current gain	h _{FE(1)} *	V _{CE} =10V, I _C =1mA	100			
	h _{FE(2)} *	V _{CE} =10V, I _C =250mA	100		300	
	h _{FE(3)} *	V _{CE} =10V, I _C =0.5A	60			
	h _{FE(4)} *	V _{CE} =10V, I _C =1A	20			
Collector-emitter saturation voltage	V _{CE(sat)1} *	I _C =500mA, I _B =50mA			0.3	V
	V _{CE(sat)2} *	I _C =1A, I _B =100mA			0.6	V
Base-emitter saturation voltage	V _{BE(sat)} *	I _C =1A, I _B =100mA			1.15	V
Base-emitter voltage	V _{BE} *	V _{CE} =10V, I _C =1A			1	V
Transition frequency	f _T	V _{CE} =10V, I _C =50mA, f=100MHz	150			MHz
Collector output capacitance	C _{ob}	V _{CB} =10V, I _E =0, f=1MHz			10	pF

*Pulse test: pulse width ≤300μs, duty cycles ≤ 2.0%.

Typical Characteristics



SOT-23 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Bipolar Transistors - BJT category](#):

Click to view products by [FUXINSEMI manufacturer](#):

Other Similar products are found below :

[BC559C](#) [MCH4017-TL-H](#) [MMBT-2369-TR](#) [BC546/116](#) [NJVMJD148T4G](#) [NTE16](#) [NTE195A](#) [IMX9T110](#) [2N4401-A](#) [2N6728](#) [2SA1419T-TD-H](#) [2SA2126-E](#) [2SB1204S-TL-E](#) [FMC5AT148](#) [2N2369ADCSM](#) [2N2907A](#) [2N3904-NS](#) [2N5769](#) [2SC4618TLN](#) [CPH6501-TL-E](#) [MCH4021-TL-E](#) [US6T6TR](#) [BAX18/A52R](#) [BC556/112](#) [IMZ2AT108](#) [MMST8098T146](#) [UMX21NTR](#) [MCH6102-TL-E](#) [TTA1452B,S4X\(S](#) [2N3879](#) [NTE13](#) [NTE282](#) [NTE323](#) [NTE350](#) [NTE81](#) [JANTX2N2920L](#) [JANTX2N3735](#) [JANSR2N2222AUB](#) [CMLT3946EG TR](#) [SNSS40600CF8T1G](#) [2N6987](#) [CMLT3906EG TR](#) [GRP-DATA-JANS2N2907AUB](#) [GRP-DATA-JANS2N2222AUA](#) [MMDT3946FL3-7](#) [2N4240](#) [JANS2N3019](#) [MSB30KH-13](#) [2N2221AUB](#) [2SD1815T-TL-E](#)